

RJK0629DPN

60V, 85A, $4.5m\Omega$ max. N Channel Power MOS FET High-Speed Switching Use

R07DS1062EJ0200 (Previous: REJ03G1873-0100)

revious: REJU3G1873-0100)
Rev.2.00

Apr 09, 2013

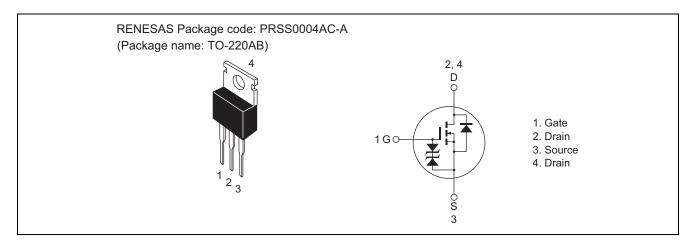
Features

• V_{DSS}: 60 V

• R_{DS(on)}: 4.5 mΩ (Max)

• I_D: 85 A

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit	
Drain to source voltage	V _{DSS}	60	V	
Gate to source voltage	V _{GSS}	±20	V	
Drain current	I _D	85	А	
Drain peak current	I _D (pulse) Note1	340	А	
Body-drain diode reverse drain current	I _{DR}	85	А	
Body-drain diode reverse drain peak current	I _{DR} (pulse) Note1	340	А	
Avalanche current	I _{AP} Note2	55	А	
Channel dissipation	Pch Note3	100	W	
Channel to case thermal impedance	θch-c	1.25	°C/W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. $PW \le 10 \mu s$, duty cycle $\le 1\%$

2. Tc = 25°C, Tch \leq 150°C, L = 100 μH

3. Value at Tc = 25°C

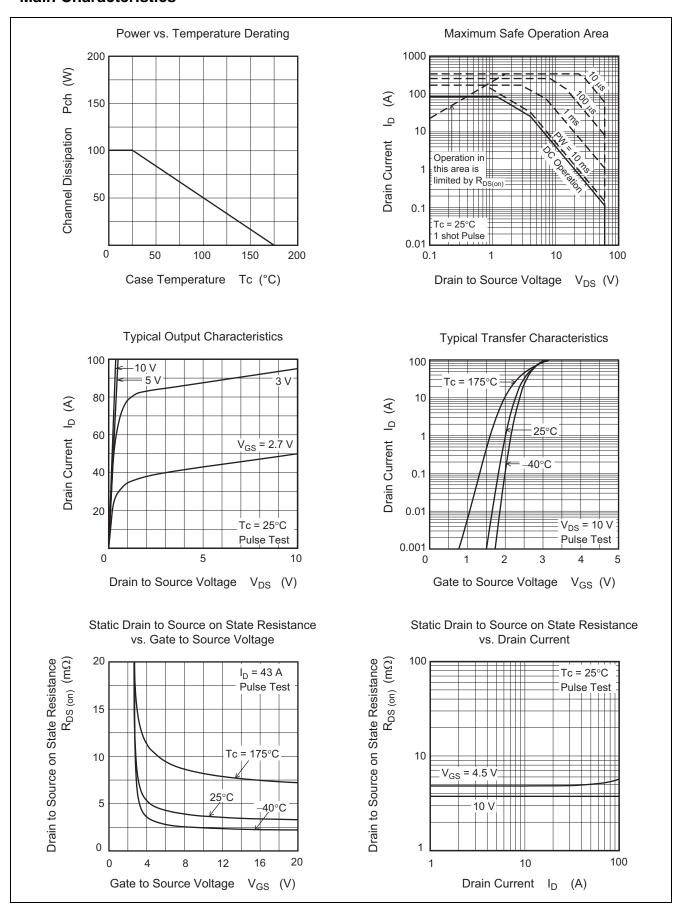
Electrical Characteristics

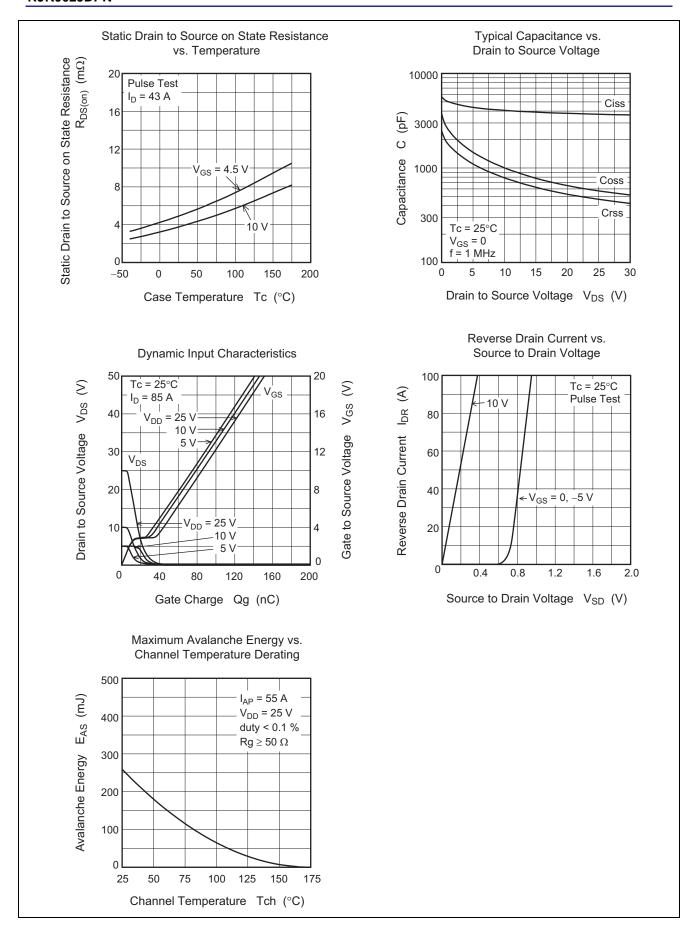
 $(Ta = 25^{\circ}C)$

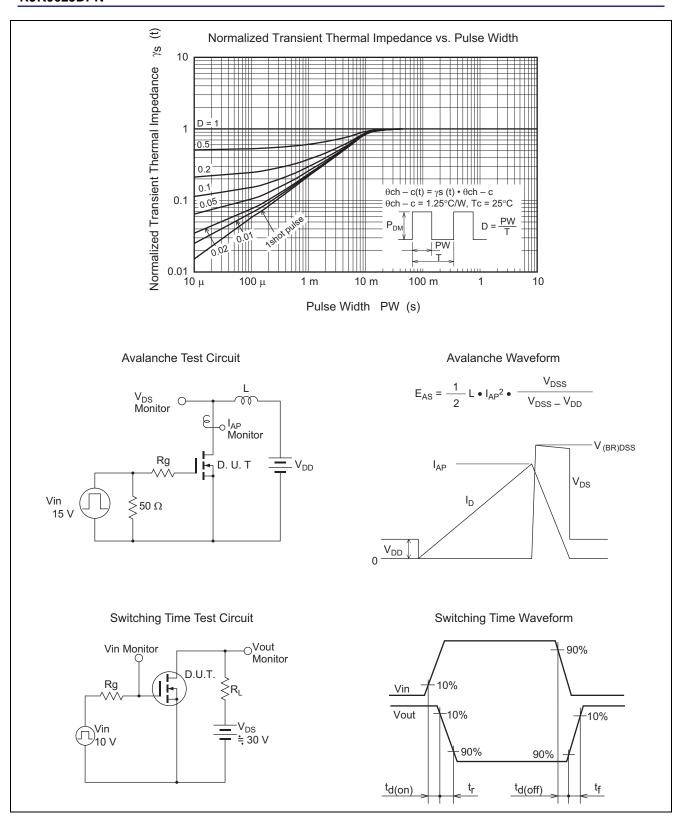
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 100 \ \mu A, \ V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.0	_	2.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state voltage	V _{DS(on)}	_	161	194	mV	$I_D = 43A$, $V_{GS} = 10 \text{ V}^{\text{Note}4}$
Static drain to source on state	R _{DS(on)}	_	3.75	4.5	mΩ	$I_D = 43A$, $V_{GS} = 10 \text{ V}^{\text{Note}4}$
resistance		_	4.9	6.6	mΩ	$I_D = 43 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note}4}$
Input capacitance	Ciss	_	4100	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0$
Output capacitance	Coss	_	1000	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	780	_	pF	
Total gate charge	Qg	_	85	_	nC	$V_{DD} = 25 \text{ V}, V_{GS} = 10 \text{ V},$
Gate to source charge	Qgs	_	11	_	nC	I _D = 85 A
Gate to drain charge	Qgd	_	25	_	nC	
Turn-on delay time	t _{d(on)}	_	20	_	ns	$V_{DD} = 30V, I_{D} = 43A,$
Rise time	t _r	_	40	_	ns	$V_{GS} = 10 \text{ V}, R_{G} = 4.7 \Omega$
Turn-off delay time	t _{d(off)}	_	100	_	ns	
Fall time	t _f	_	40	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.92	1.2	V	$I_F = 85 \text{ A}, V_{GS} = 0^{\text{Note}4}$
Body-drain diode reverse recovery time	t _{rr}	_	50	_	ns	$I_F = 85 \text{ A}, V_{GS} = 0,$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Note: 4. Pulse test

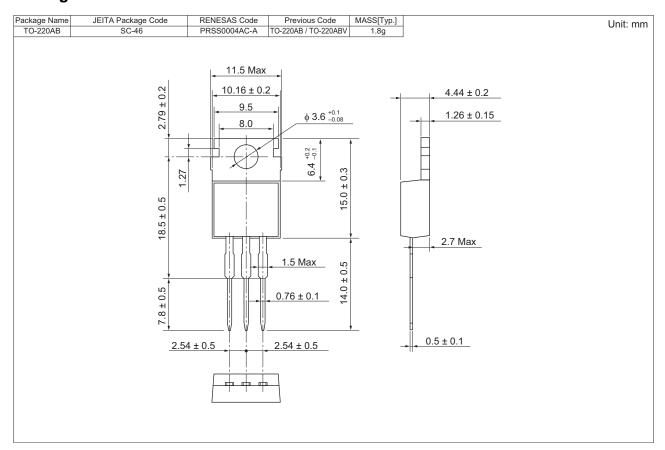
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK0629DPN-00-T2	600 pcs	Box (Tube)

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